

TMS2732A 32,768-BIT UV ERASABLE PROGRAMMABLE READ-ONLY MEMORY

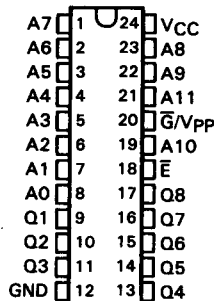
AUGUST 1983—REVISED FEBRUARY 1988

EPROMs/PROMs/EEPROMs

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- Organization . . . 4096 × 8
- Single 5-V Power Supply
- All Inputs/Outputs Fully TTL Compatible
- Max Access/Min Cycle Times
TMS2732A-17 170 ns
TMS2732A-20 200 ns
TMS2732A-25 250 ns
TMS2732A-45 450 ns
- Low Standby Power Dissipation . . .
158 mW (Maximum)
- JEDEC Approved Pinout . . . Industry
Standard
- 21-V Power Supply Required for
Programming
- N-Channel Silicon-Gate Technology
- PEP4 Version Available with 168 Hour
Burn-In, and Extended Guaranteed Operating
Temperature Range from -10°C to 85°C
(TMS2732A-__JP4)

J PACKAGE
(TOP VIEW)



PIN NOMENCLATURE

A0-A11	Address Inputs
E	Chip Enable
$\bar{G}/V_{pp}$	Output Enable/21 V
GND	Ground
Q1-Q8	Outputs
VCC	5-V Power Supply

description

The TMS2732A is an ultraviolet light-erasable, electrically programmable read-only memory. It has 32,768 bits organized as 4,096 words of 8-bit length. The TMS2732A only requires a single 5-volt power supply with a tolerance of $\pm 5\%$.

The TMS2732A provides two output control lines: Output Enable ($\bar{G}/V_{pp}$) and Chip Enable ($\bar{E}$). This feature allows the $\bar{G}/V_{pp}$ control line to eliminate bus contention in multibus microprocessor systems. The TMS2732A has a power-down mode that reduces maximum power dissipation from 657 mW to 158 mW when the device is placed on standby.

This EPROM is supplied in a 24-pin dual-in-line ceramic package and is designed for operation from 0°C to 70°C. The TMS2732A is also offered in the PEP4 version with an extended guaranteed operating temperature range of -10°C to 85°C and 168 hour burn-in (TMS2732A-__JP4).

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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INSTRUMENTS

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operation

The six modes of operation for the TMS2732A are listed in the following table.

FUNCTION (PINS)	MODE					
	Read	Output Disable	Power Down (Standby)	Program	Program Verification	Inhibit Programming
$\bar{E}$ (18)	V_{IL}	$X^{\dagger}$	V_{IH}	V_{IL}	V_{IL}	V_{IH}
$\bar{G}/V_{PP}$ (20)	V_{IL}	V_{IH}	$X^{\dagger}$	21 V	V_{IL}	21 V
V_{CC} (24)	5 V	5 V	5 V	5 V	5 V	5 V
Q1-Q8 (9 to 11, 13 to 17)	Q	HI-Z	HI-Z	D	Q	HI-Z

$^{\dagger}X = V_{IH} \text{ or } V_{IL}$

read/output disable

The two control pins ($\bar{E}$ and $\bar{G}/V_{PP}$) must have low-level TTL signals in order to provide data at the outputs. Chip enable ($\bar{E}$) should be used for device selection. Output enable ($\bar{G}/V_{PP}$) should be used to gate data to the output pins.

power down

The power-down mode reduces the maximum power dissipation from 657 mW to 158 mW. A TTL high-level signal applied to $\bar{E}$ selects the power-down mode. In this mode, the outputs assume a high-impedance state independent of $\bar{G}/V_{PP}$.

erasure

The TMS2732A is erased by exposing the chip to shortwave ultraviolet light that has a wavelength of 253.7 nanometers (2537 angstroms). The recommended minimum exposure dose (UV intensity $\times$ exposure time is fifteen watt-seconds per square centimeter. The lamp should be located about 2.5 centimeters (1 inch) above the chip during erasure. After erasure, all bits are at a high level. It should be noted that normal ambient light contains the correct wavelength for erasure. Therefore, when using the TMS2732A, the window should be covered with an opaque label.

programming

Note that the application of a voltage in excess of 22 V to $\bar{G}/V_{PP}$ may damage the TMS2732A.

After erasure (all bits in logic 1 state), logic 0s are programmed into the desired locations. A logic 0 can only be erased by ultraviolet light. In the program mode, $\bar{G}/V_{PP}$ is taken from a TTL low level to 21 V and data to be programmed are applied in parallel to output pins Q1-Q8. The location to be programmed is addressed. Once data and addresses are stable, a 10-millisecond TTL low-level pulse is applied to $\bar{E}$. The maximum width of this pulse is 11 milliseconds. The programming pulse must be applied at each location that is to be programmed. Locations may be programmed in any order.

Several TMS2732As can be programmed simultaneously by connecting them in parallel and following the programming sequence previously described.

program inhibit

The program inhibit is useful when programming multiple TMS2732As connected in parallel with different data. Program inhibit can be implemented by applying a high-level signal to $\bar{E}$ of the device that is not to be programmed.

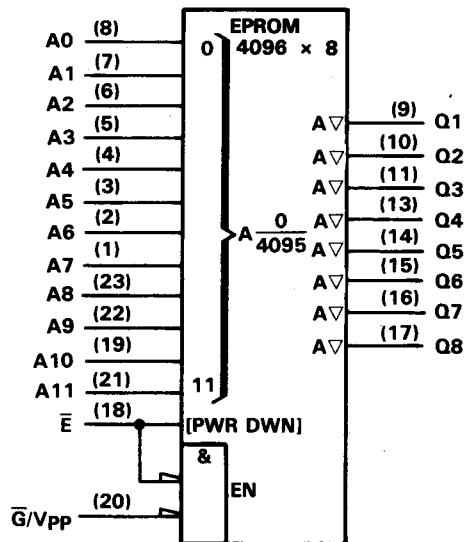
program verify

After the EPROM has been programmed, the programmed bits should be verified. To verify bit states, $\bar{G}/V_{PP}$ and $\bar{E}$ are set to V_{IL} .

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logic symbol†



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†This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC}	−0.3 V to 7 V
Supply voltage range, V_{PP}	−0.3 V to 22 V
Input voltage range (except program)	−0.3 to 7 V
Output voltage range	−0.3 V to 7 V
Operating free-air temperature range	0°C to 70°C
Storage temperature range	−65°C to 150°C

‡Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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recommended operating conditions

PARAMETER	MIN	NOM	MAX	UNIT
V _{CC} Supply voltage (see Note 1)	4.75	5	5.25	V
V _{pp} Supply voltage (see Note 2)	V _{CC}			V
V _{IH} High-level input voltage	2	V _{CC} + 1		V
V _{IL} Low-level input voltage	-0.1	0.8		V
T _A Operating free-air temperature	0	70		°C

- NOTES: 1. V_{CC} must be applied before or at the same time as V_{pp} and removed after or at the same time as V_{pp}. The device must not be inserted into or removed from the board when V_{pp} or V_{CC} is applied.
2. V_{pp} can be connected to V_{CC} directly (except in the program mode). V_{CC} supply current in this case would be I_{CC} + I_{pp}. During programming, V_{pp} must be maintained at 21 V (±0.5 V).

electrical characteristics over full ranges of recommended operating conditions

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
V _{OH} High-level output voltage	I _{OH} = -400 µA	2.4		V
V _{OL} Low-level output voltage	I _{OL} = 2.1 mA		0.45	V
I _I Input current (leakage)	V _I = 0 V to 5.25 V		±10	µA
I _O Output current (leakage)	V _O = 0.4 V to 5.25 V		±10	µA
I _{CC1} V _{CC} supply current (standby)	$\bar{E}$ at V _{IH} , $\bar{G}/V_{pp}$ at V _{IL}		30	mA
I _{CC2} V _{CC} supply current (active)	$\bar{E}$ and $\bar{G}/V_{pp}$ at V _{IL}		125	mA

capacitance over recommended supply voltage range and operating free-air temperature range, f = 1 MHz†

PARAMETER	TEST CONDITIONS	TYP‡	MAX	UNIT
C _i Input capacitance	All except $\bar{G}/V_{pp}$	6	9	pF
	$\bar{G}/V_{pp}$		20	
C _o Output capacitance	V _O = 0 V	8	12	pF

†These parameters are tested on sample basis only.

‡Typical values are at T_A = 25°C and nominal voltages.

switching characteristics over recommended supply voltage range and operating free-air temperature range

PARAMETER	TEST CONDITIONS	TMS2732A-17		TMS2732A-20		TMS2732A-25		TMS2732A-45		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _a (A) Access time from address	C _L = 100 pF, 1 Series 74 TTL load, t _r ≤ 20 ns, t _f ≤ 20 ns, See Figure 1 and Note 3	170		200		250		450		ns
t _a (E) Access time from $\bar{E}$		170		200		250		450		ns
t _{en} (G) Output enable time from $\bar{G}/V_{pp}$		65		70		100		150		ns
t _{dis} † Output disable time from $\bar{E}$ or G, whichever occurs first		0	60	0	60	0	85	0	130	ns
t _v (A) Output data valid time after change of address, $\bar{E}$, or $\bar{G}/V_{pp}$, whichever occurs first		0		0		0		0		ns

NOTE 3: For all switching characteristics and timing measurements, input pulse levels are 0.40 V and 2.4 V. Input and output reference levels are 0.8 V and 2.0 V.

†Value calculated from 0.5 V delta to measured output level. This parameter is only sampled, not 100% tested.

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recommended conditions for programming, $T_A = 25^\circ\text{C}$ (see Note 4)

	MIN	NOM	MAX	UNIT
V_{CC} Supply voltage	4.75	5	5.25	V
V_{pp} Supply voltage	20.5	21	21.5	V
V_{IH} High-level input voltage	2		$V_{CC}+1$	V
V_{IL} Low-level input voltage	-0.1		0.8	V
$t_w(E)$ $\bar{E}$ pulse duration	9	10	11	ms
$t_{su}(A)$ Address setup time	2			μs
$t_{su}(D)$ Data setup time	2			μs
$t_{su}(V_{pp})$ $\bar{G}/V_{pp}$ setup time	2			μs
$t_h(A)$ Address hold time	0			μs
$t_h(D)$ Data hold time	2			μs
$t_h(V_{pp})$ $\bar{G}/V_{pp}$ hold time	2			μs
$t_{rec}(PG)$ $\bar{G}/V_{pp}$ recovery time	2			μs
$t_r(PG)G$ $\bar{G}/V_{pp}$ rise time during programming	50			ns
t_{EHD} Delay time, data valid after $\bar{E}$ low			1	μs

NOTE 4: When programming the TMS2732A, connect a 0.1 μF capacitor between $\bar{G}/V_{pp}$ and GND to suppress spurious voltage transients which may damage the device.

programming characteristics, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH} High-level input voltage		2		$V_{CC}+1$	V
V_{IL} Low-level input voltage		-0.1		0.8	V
V_{OH} High-level output voltage (verify)	$I_{OH} = -400 \mu\text{A}$	2.4			V
V_{OL} Low-level output voltage (verify)	$I_{OL} = 2.1 \text{ mA}$			0.45	V
I_I Input current (all inputs)	$V_I = V_{IL}$ or V_{IH}			10	μA
I_{pp} Supply current	$\bar{E} = V_{IL}, \bar{G} = V_{pp}$			50	mA
I_{CC} Supply current				125	mA
$t_{dis}(PR)$ Output disable time		0		130	ns

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PARAMETER MEASUREMENT INFORMATION

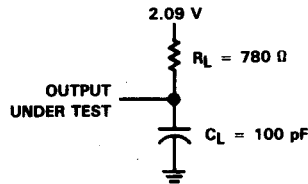
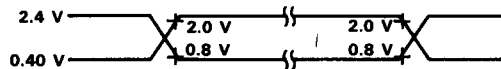


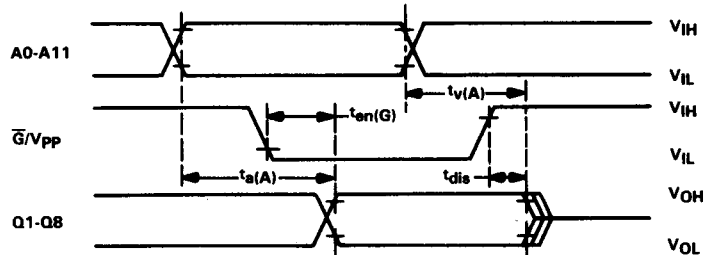
FIGURE 1. TYPICAL OUTPUT LOAD CIRCUIT

AC testing input/output wave forms

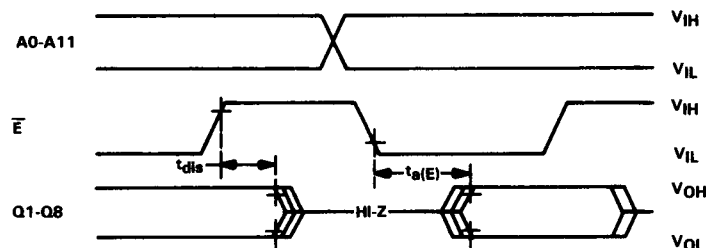


A.C. testing inputs are driven at 2.4 V for logic 1 and 0.4 V for logic 0. Timing measurements are made at 2.0 V for logic 1 and 0.8 V for logic 0 for both inputs and outputs.

read cycle timing



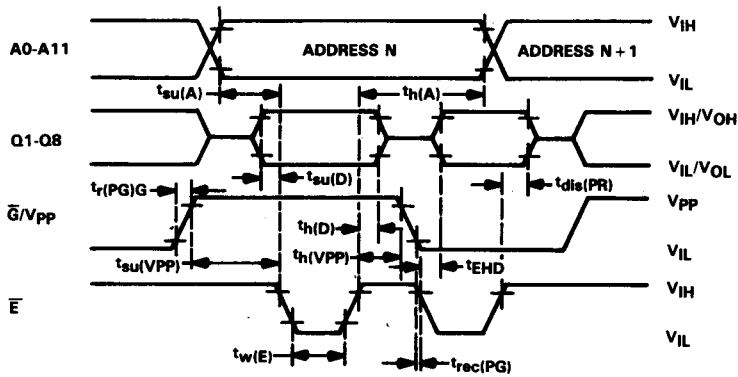
standby mode



NOTE 3: For all switching characteristics and timing measurements, input pulse levels are 0.40 V and 2.4 V. Input and output timing reference levels are 0.8 V and 2.0 V.

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program cycle timing



NOTE 3: For all switching characteristics and timing measurements, input pulse levels are 0.40 V and 2.4 V. Input and output timing reference levels are 0.8 V and 2.0 V.

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Designing and Manufacturing Surface Mount Assemblies

T-90-20

Elizabeth Gunther, Charles Hutchins, and Paul Peterson

The competitive nature of the semiconductor industry has driven vendors to minimize the size of electronic components, so that more functions can be achieved in a given volume. In addition, improved electrical performance, decreased mass, and the potential for lower system cost are all by-products of compacted packaging and circuitry which hold interest to component manufacturers and users alike.

Surface Mount Technology (SMT) offers an excellent method of reducing component size. A typical memory array can be reduced to 50 percent of its original PWB size with single-sided mounting, and 25 to 30 percent with double-sided mounting. Logic designs cannot achieve the same dramatic reduction, but decreases up to 40 to 60 percent can be achieved for single-sided and double-sided assemblies respectively.

The key design and manufacturing process issues must be understood in order to fully reap the benefits of Surface Mount Technology. This article gives a general overview of the key aspects of design, process, and manufacturing of surface mounted assemblies, and offers surface mount as an opportunity to lower a system's cost without sacrificing reliability.

Components

Most surface mount components are at least one-third the size of the comparable through-hole mounted device (Figure 1). The 68-pin chip carrier is approximately one square inch, while the 64-pin DIP is approximately three square inches. The 20-pin chip carrier is slightly larger than 0.1 square inch, while the 20-pin DIP is 0.3 square inch. Similarly, other IC packages are reduced to approximately one-third the size of comparable lead count packages. The passive components

occupy approximately one-tenth the board area, and this is why they have been used in most small consumer products built in the last couple of years.

There were many references in the recent past to problems with component availability, cost, and standardization. This area of SMT has probably received more attention than any other. Several recent magazine articles now state that significantly more components (particularly actives) are now available and that cost parity has been achieved on most of them. The effort by various industry committees on standardization has also been effective.

Thus, although more needs to be accomplished in these areas, a designer can begin a project with confidence that there will be no insurmountable barriers in this area. There are several consultants and subcontract assembly companies to assist in this effort. It is strongly recommended that all new designs utilize some form of SMT, particularly when space is an important consideration.

Process

The process to manufacture a surface mount assembly (SMA) is very simple. It consists of four basic steps, as shown in Figure 2. First, the solder paste is screened on the PWB. Then the component is placed on the board, with due care to get it positioned correctly. Typical geometries require placement accuracy of less than plus/minus 4 mils. Next the solder is reflowed with either a vapor phase or infrared system. Finally, the assembly is cleaned and is now ready for test. This process, although simple in concept, relies on board and component planarity and solderability. These are easily achievable with the chip carriers and memory modules we will discuss later.

Texas Instruments has installed a Surface Mount Technology Center at its plant in Houston, Texas. At this center, we have a complete and flexible engineering line to assist our customers in converting to Surface Mount Technology.

The engineering line is equipped with a screen printer, pick and place system, vapor phase reflow, and clean-up station that will easily handle PWBs up to 9" x 10". Larger boards up to 14" x 16" can be processed with some additional care. TI uses this engineering line to produce its prototype and demo boards. It is also available to any of TI's customers, free of charge, for use in building test or prototype boards.

The effectiveness of the assembly process can be characterized by the number of unacceptable solder joints formed during the process. Unacceptable joints are defined by their electrical and mechanical (strength and reliability) characteristics. The major problem is open solder joints, followed by bridging and misregistration.

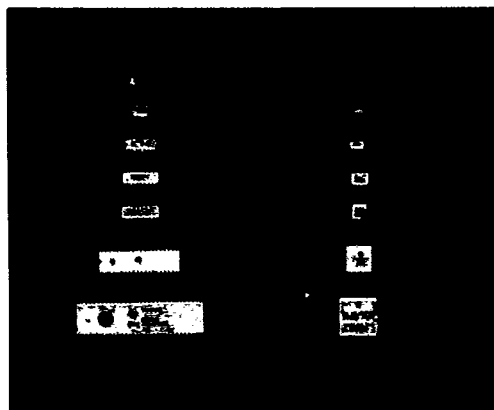


Figure 1. Component Site Reduction

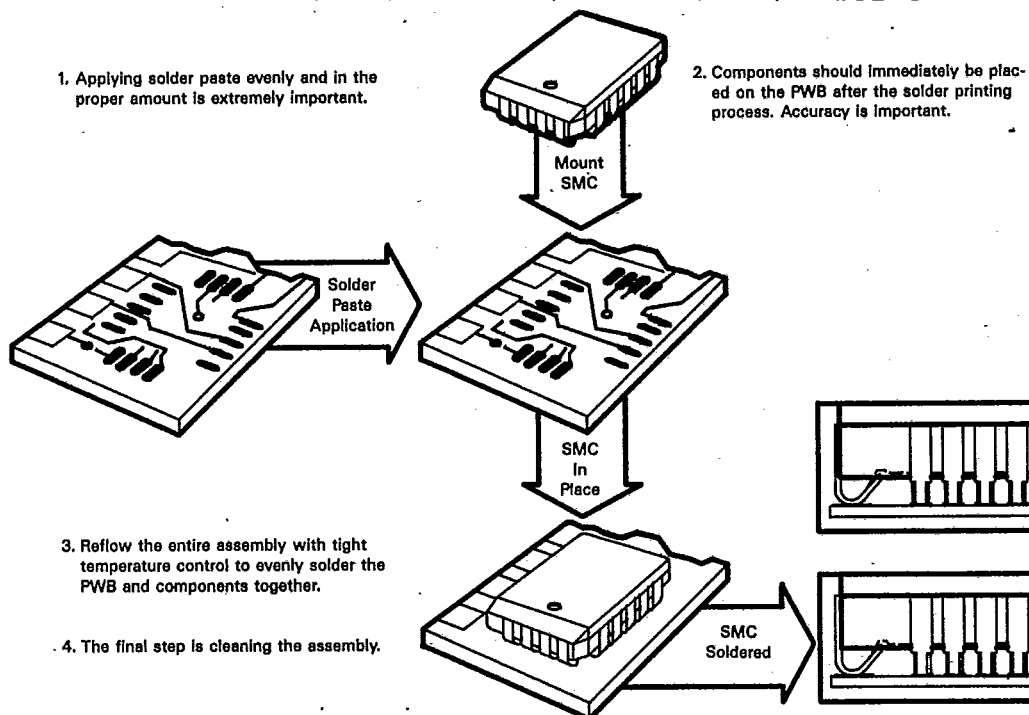


Figure 2. Basic Process Steps

Open circuits are detected at electrical test and are the first defects detected after soldering. At Texas Instruments, 10 PPM or less is the desirable defect level. Several factors that contribute to open solder joints were identified during production start-up. Lead tip planarity of the J-leaded plastic chip carriers is the most important factor in obtaining acceptable process yields. Lead position, lead finish, solder paste composition, and PWB solderability affect process yield as well.

Experiments in which lead tip planarity was confined to specific limits between 1 to 7 mils indicate that a 2 mil planarity requirement produces acceptable results with the process currently in use. Little gain in yield was noted at a 1 mil planarity requirement.

Another interesting result showed that silver in the process, either as a lead finish or in the solder paste, improves yields significantly. One explanation may have to do with the dynamics of the solder during the reflow process as they are affected by the different surface forces acting in the silver and non-silver process.

Design

The design of the PWB, in addition to providing the component interconnections, will provide the proper amount and correct placement of solder paste for a strong fillet formation. The wave soldering process, by comparison, provides a semi-infinite amount of solder, whereas the SMT process will provide only a predetermined amount. Thus, the component connection pad must be correctly placed and be of the proper size.

Further, consideration must be given for inspection, testing, and rework. The density achievable can lead to severe problems at these points if understanding and due care are not exercised in the design. The project team should include members from manufacturing, testing, QA, and purchasing, in addition to the design engineers, from the start. The design and processing of test boards is strongly recommended to provide experience and direction for the major project.

A very practical set of design guidelines is given in Figure 3. These have been used on a number of SMT designs and have given good results. With proper manufacturing techniques as described later, a high yield can be achieved. Component spacings should be approximately equal to the height of the tallest component. This allows an angle of 45 degrees for visual inspection of test probes.

Figure 4 shows the standard footprint for all Small Outline (SO) packages. The larger and more important fillet of an SO package is on the inside of the gull-wing lead. The solder pad, or land, should therefore be designed to extend

slightly under the body of the package in order to optimize this fillet. From Table 1 we can see all packages have 50 mil centers with 25 mil spacings between lands. This allows the designer enough space to put traces between pads, and also reduces the occurrence of solder bridging of adjacent lands. Table 1 also summarizes the suggested land lengths and placement, depending on the terminal count of the SO. While not an absolute solution, these land sizes offer a conservative design solution that will meet most vendors' specifications and provide a mechanically and electrically sound solder joint.

- Geometries
 - Trace Width/Space
 - IC Lead Solder Pad Size
 - Via Hole Size
 - Via Pad Size
 - Cap/Resistor Pad Size
- Solder Mask

8/8 MIL Min., 10/10 MIL Typ.
 25 ± 5 MIL × 70 ± 10 MIL
 20 MIL DIA
 40 MIL DIA
 W = MAX Dimensions of Component
 L = 20 MIL Beyond Metallization
 10 MIL Inside Metallization
 5 MIL Larger than IC/Component Pad

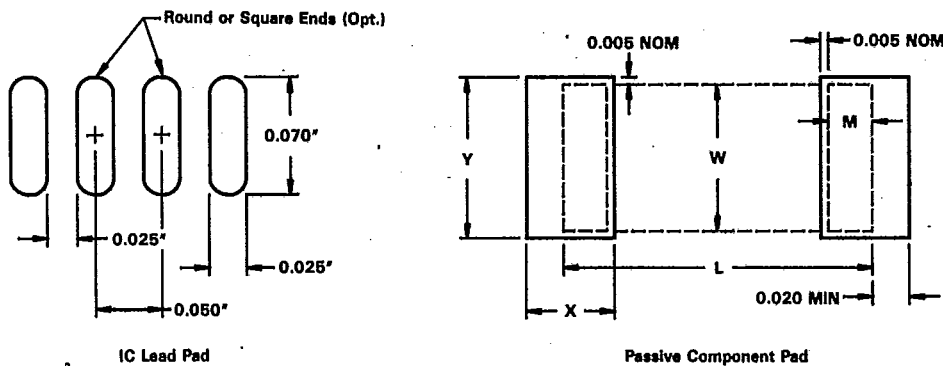


Figure 3. PWB Design Guidelines

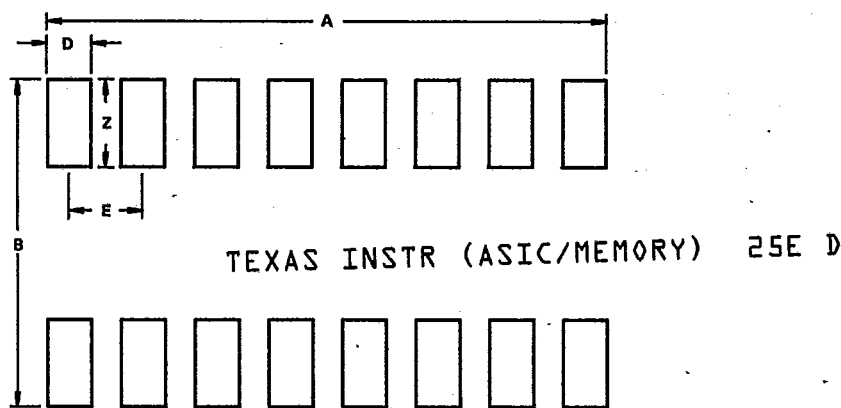


Figure 4. Standard SOIC Footprint

Table 1. SOIC Footprint Dimensions

No. of Terminals	A	B	Z	D	E
8	.175	.250	.050	.025	.050
14	.325	.250	.050	.025	.050
16	.375	.250	.050	.025	.050
20	.475	.430	.070	.025	.050
24	.575	.430	.070	.025	.050

TEXAS INSTR (ASIC/MEMORY) 25E D

Test	4164A PLCC	4164 DIP	Units
Life Test, 125°C	42	64	Fits*—60% UCL
85°C/85% RH	0.17	0.37	%/1000 Hours
Autoclave	0.17	0.98	%/240 Hours
T/C—85/150	0.52	1.44	%/1000 Cycles
T/C 0/125	0.0	0.0	%/2000 Cycles

*Derated to 55°C Assuming 0.5EV Activation Energy

Figure 5. Failure Rate Comparison
4164A PLCC VS DIP

Manufacturing

The SMT manufacturing area must have the following basic equipment:

- Solder Paste Printer
- Component Pick and Place Machine
- Solder Paste Reflow Machine
- Clean-up System
- Inspection/Process Control Aids
- Electrical Test

The criteria for choosing the above is determined mainly by the size(s) and quantity of PWBs per month, the gross number of components per PWB, and the number of different components per PWB.

The size of the largest PWB is an important criterion in the choice of all of the major items. The printer, pick and place, reflow, and clean-up must all be able to handle it with no difficulty or process nonuniformity. The number and size of the various PWBs that may be produced will secondarily be considered for ease of set up and changeover in the printer and pick and place. The pick and place machine(s) will

probably be the most expensive item in the list above and therefore, should get the most attention.

The gross number of components and PWBs will provide data for choosing the pick and place. Component per hour placement speed should be checked in actual operation, as the interrelationship may affect ultimate speed. The number of different components per board will determine how many feeders and what types of feeders will be required. This is a very key issue, as well as the accuracy of placement.

Reflow

The solder reflow is easily achieved with any of the commercially available equipment. Subtle differences between vapor phase, either batch or in-line, and infrared are overshadowed by the choice of solder paste and the solderability/planarity issue. A batch vapor phase is extremely flexible for different sizes of boards with different component counts. The in-line vapor phase is a good choice for a more automated processing line with standard or similar sized boards. The infrared has the advantage of being less expensive to operate, but requires more alteration to set up the time-temperature profile for a different size PWB. This would be a minimal problem on a manufacturing line building high volumes of the same board.

Clean-up

The most popular flux for SMT is the mildly activated rosin flux (RMA). This was developed in the days of vacuum tube assembly when clean-up was next to impossible. It is noncorrosive but provides sufficient fluxing action for good quality components and PWBs. Thus it is the preferred choice for SMAs with small spacings under most passives and SOICs, where complete cleaning is difficult. A mild solvent, such as Freon TMS, is generally sufficient to achieve a good visual cleanup, and there are several systems available that provide hot vapor, spray, or ultrasonic de-fluxing.

Reliability

With the smaller surface mount packages, there is some concern about component reliability. Texas Instruments addressed the overall DRAM reliability issue several years ago. Through an extensive task force effort, the major problems of the life test, humidity performance, and temperature cycle were identified. The best solutions to these problems required several changes in the design and process of the silicon chip. In doing so, the reliability of the DRAM chip became independent of the package used. Thus, the 64K DRAM in the plastic chip carrier package performs equivalently to the same chip in a DIP as shown in Figure 5. Similar data is available on most semiconductor ICs.

An additional reliability concern originates in the surface mount solder reflow process, which submits components to higher reflow temperatures more suddenly than the wave-soldering methods of DIP components, with oftentimes repeated reflow cycles for rework and repair.

The best method for resolving this issue involves comparing the temperature-time differential of the vapor phase or infrared solder reflow process to the standard temperature

cycling reliability tests to which surface mount components are routinely submitted. Figures 6 and 7 show temperature profiles of the vapor phase and infrared solder reflow processes. In the vapor phase process, the maximum temperature change with time is:

$$\frac{215^{\circ}\text{C} - 25^{\circ}\text{C}}{45 \text{ sec}} = \frac{190^{\circ}\text{C}}{45 \text{ sec}}$$

equating approximately 4°C/sec. The infrared solder reflow method submits the ICs to a similar, yet less severe temperature over time change of 3°C/second. Comparing these temperature profile ramp-ups to that which a surface mount component undergoes in a temperature cycling reliability test proves that there should be no concern over damage to the component during reflow. In the temp cycling test, the surface mount components were submitted to 1000 cycles of sudden cycling from 150°C to -65°C within three seconds. This represents a temperature-time differential of:

$$\frac{150^{\circ}\text{C} - (-65^{\circ}\text{C})}{3} = \frac{215^{\circ}\text{C}}{3 \text{ sec}} = \frac{70^{\circ}\text{C}}{\text{sec}}$$

with less than 0.5 percent failures.

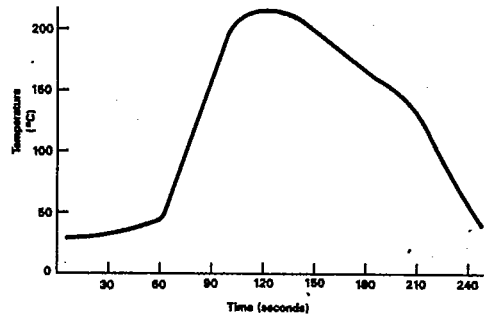


Figure 6. Typical Temperature Profile for In-Line Vapor Phase Reflow

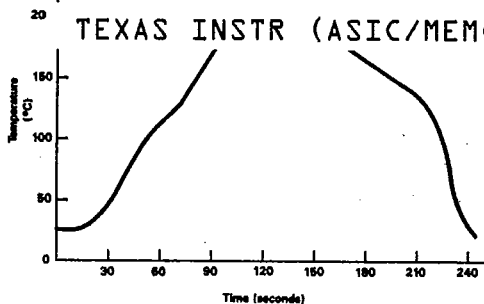


Figure 7. Typical IR Reflow System Profile

Since the surface mounted components were able to withstand a 70°C/second temperature change of 1000 cycles, they should be able to withstand the less severe conditions of a 4°C/second damage during reflow without reliability degradation.

Another concern in the solder reflow processing of surface mount components is the dwell time in reflow temperatures of 215°C or above. The dwell time for a small PWB populated with surface mount devices is about 20 seconds. For a larger board of about 10"×12" up to 50 seconds is needed for reflow. A generalized component degradation curve, relating accumulated time and temperature, can be assumed to exist. The shape of the curve for this discussion is assumed to be a decaying parabolic for simplicity and conservatism. There are two generally known points of this curve. The flame retardant mold compound (FRMC) of a plastic package starts to break down at 300°C in two to three seconds. Also, the molding and curing of a surface mount device is performed over several hours at 175°C. These two points are shown on the generalized curve shown in Figure 8, with the "safe" region being the area under the curve. Two points that fall within this region are the industry standard practice of solder dipping leads of several types of ICs, and of the soldering plastic devices on the bottom with Type III surface mount assembly, each submerges the component for three to four seconds in a solder wave.

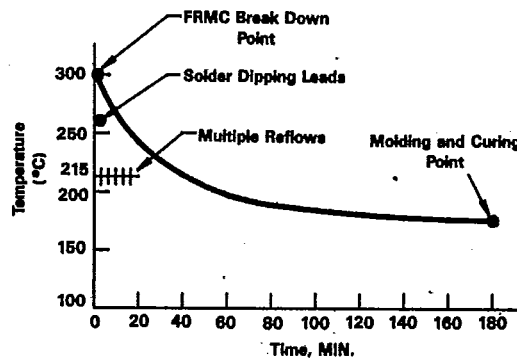


Figure 8. General Plastic Degradation Curve

Summary

Surface mount assembly techniques provide a significant advantage in cost, volume, and reliability over the current "thru-hole" technology. These are well documented, and the manufacturing equipment and related products are becoming readily available to support new production lines. Also, as experience grows, improved products and ideas are developed from the cooperative efforts of vendors and users in standardization organizations and in problem-solving sessions. The broad selection of package types and product technologies available now are sufficient to begin conversion of existing electronic system products for size reduction or feature enhancement. Definitely, new products should be designed with surface mount technology.